

Germanium tin could mean better and cheaper infrared cameras in smartphones

September 19 2014, by Matt McGowan



Fisher Yu, University of Arkansas

Engineering researchers at the University of Arkansas have fabricated a new semiconductor material—germanium tin deposited in layers on a substrate of silicon—that could be used to build better and less expensive infrared cameras for smartphones and vehicles.

"The performance of these simple structures indicates a promising future for [germanium](#) tin photodetectors," said Fisher Yu, associate

professor of [electrical engineering](#). "The crystalline growth of these samples in a commercially available reactor allows for these infrared detectors to be available for immediate commercial implementation."

Yu and colleagues Wei Du, postdoctoral fellow in the Department of Electrical Engineering; Benjamin Conley, doctoral student in the microelectronics-photonics graduate program; and Hameed Naseem, professor of electrical engineering, built devices using a process allowing thin films of germanium tin to be deposited on silicon, without damaging integrated circuits.

The researchers tested and measured the device at various percentages of material composition – 0.9, 3.2 and 7.0 – and at temperatures ranging from 77 to 300 on the Kelvin scale. Kelvin is a unit of thermodynamic temperature equal in magnitude to the degree Celsius. The researchers wanted to explore how the device would perform at room temperature for future night vision applications.

"This work will bring us much closer to the quality of images you find in military and satellite equipment," Yu said.

Only a few other research groups are working with germanium tin to produce [semiconductor material](#) for computer chips and electronics. The material has potential for other applications, including lasers and high efficiency solar cells.

The findings have been published in a recent issue of *Optics Express*.

More information: Temperature dependent spectral response and detectivity of GeSn photoconductors on silicon for short wave infrared detection

, *Optics Express*, www.opticsinfobase.org/oe/abstract.cfm?URI=oe-22-13-15639

Provided by University of Arkansas

Citation: Germanium tin could mean better and cheaper infrared cameras in smartphones (2014, September 19) retrieved 27 April 2024 from <https://phys.org/news/2014-09-germanium-tin-cheaper-infrared-cameras.html>

This document is subject to copyright. Apart from any fair dealing for the purpose of private study or research, no part may be reproduced without the written permission. The content is provided for information purposes only.